

3A, 50V - 1000V Surface Mount Fast Recovery Rectifier

FEATURES

- Glass passivated chip junction
- Ideal for automated placement
- Fast switching for high efficiency
- Moisture sensitivity level: level 1, per J-STD-020
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

Λ	D	DI	14	$\sim \Lambda$	TI	1	M	c

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- Converter

MECHANICAL DATA

- Case: DO-214AB (SMC)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: As marked
- Weight: 0.21 g (approximately)

KEY PARAMETERS					
PARAMETER VALUE UNI					
l _F	3	Α			
V_{RRM}	50 - 1000	٧			
I _{FSM}	100	Α			
T_{JMAX}	150	°C			
Package	DO-214AB	(SMC)			



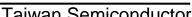






DO-214AB (SMC)

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)									
PARAMETER	SYMBOL	RS	RS	RS	RS	RS	RS	RS	UNIT
PARAMETER		3A-K	3B-K	3D-K	3G-K	3J-K	3K-K	ЗМ-К	
Marking code on the device		RS3A	RS3B	RS3D	RS3G	RS3J	RS3K	RS3M	
Repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Reverse voltage, total rms value	V _{R(RMS)}	35	70	140	280	420	560	700	V
Forward current	I _F	3						Α	
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	100					А		
Junction temperature	TJ	- 55 to +150						°C	
Storage temperature	T _{STG}	- 55 to +150					°C		





THERMAL PERFORMANCE					
PARAMETER	SYMBOL	TYP.	UNIT		
Junction-to-lead thermal resistance per diode	R _{OJL}	10	°C/W		
Junction-to-ambient thermal resistance per diode	R _{OJA}	56	°C/W		
Junction-to-case thermal resistance per diode	R _{eJC}	11	°C/W		

Thermal Performance Note: Units mounted on PCB (16mm x 16mm Cu pad test board)

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)							
PARAMETER		CONDITIONS	SYMBOL	TYP.	MAX.	UNIT	
		$I_F = 1.5A, T_J = 25^{\circ}C$		0.99	-	V	
Forward voltage per diode ⁽¹)	$I_F = 3.0A, T_J = 25^{\circ}C$	V	1.10	1.30	V	
Forward voltage per diode		I _F = 1.5A, T _J = 125°C	V _F	0.81	-	V	
		I _F = 3.0A, T _J = 125°C		0.91	1.05	V	
Deverse surrent @ reted //	Reverse current @ rated V _R per diode ⁽²⁾			-	10	μA	
Reverse current @ rated v _R			- I _R	-	250	μA	
Junction capacitance		1 MHz, V _R =4.0V	CJ	24	-	pF	
RS3A-K RS3B-K RS3D-K Reverse recovery time		I _F =0.5A , I _R =1.0A		-	150	ns	
Novolog logovory time	RS3J-K	I _{RR} =0.25A	t _{rr}	-	250	ns	
	RS3K-K RS3M-K			-	500	ns	

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Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms



DERING INFORMATION					
ORDERING CODE	PACKAGE	PACKING			
RS3A-K R7G	SMC	850 / 7" Plastic reel			
RS3A-K M6G	SMC	3,000 / 13" Plastic reel			
RS3B-K R7G	SMC	850 / 7" Plastic reel			
RS3B-K M6G	SMC	3,000 / 13" Plastic reel			
RS3D-K R7G	SMC	850 / 7" Plastic reel			
RS3D-K M6G	SMC	3,000 / 13" Plastic reel			
RS3G-K R7G	SMC	850 / 7" Plastic reel			
RS3G-K M6G	SMC	3,000 / 13" Plastic reel			
RS3J-K R7G	SMC	850 / 7" Plastic reel			
RS3J-K M6G	SMC	3,000 / 13" Plastic reel			
RS3K-K R7G	SMC	850 / 7" Plastic reel			
RS3K-K M6G	SMC	3,000 / 13" Plastic reel			
RS3M-K R7G	SMC	850 / 7" Plastic reel			
RS3M-K M6G	SMC	3,000 / 13" Plastic reel			



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.1 Forward Current Derating Curve

4 AVERAGE FORWARD CURRENT (A) 3 2 1 Heat sink 16mm x 16mm Cu pad test board 0 25 50 75 100 125 150 LEAD TEMPERATURE (C)

Fig.2 Typical Junction Capacitance

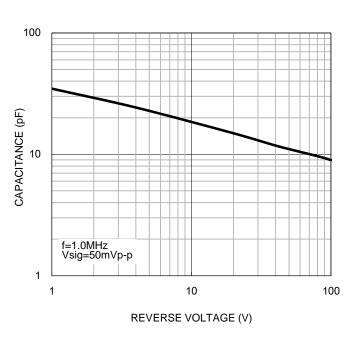


Fig.3 Typical Reverse Characteristics

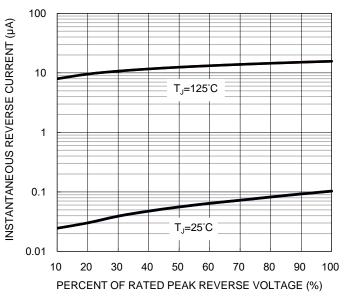
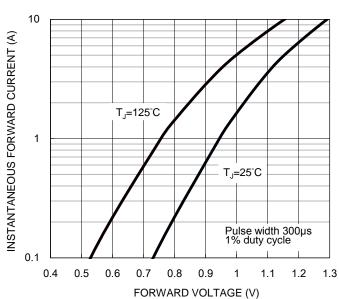


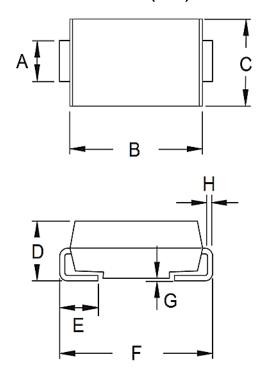
Fig.4 Typical Forward Characteristics





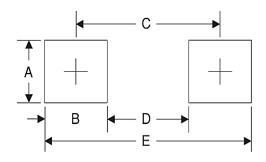
PACKAGE OUTLINE DIMENSIONS

DO-214AB (SMC)



DIM.	Unit	(mm)	m) Unit (in		
DIIVI.	Min.	Max.	Min.	Max.	
Α	2.90	3.20	0.114	0.126	
В	6.60	7.11	0.260	0.280	
С	5.59	6.22	0.220	0.245	
D	2.00	2.62	0.079	0.103	
Е	1.00	1.60	0.039	0.063	
F	7.75	8.13	0.305	0.320	
G	0.10	0.20	0.004	0.008	
Н	0.15	0.31	0.006	0.012	

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)	
А	3.30	0.130	
В	2.50	0.098	
С	6.80	0.268	
D	4.40	0.173	
Е	9.40	0.370	

MARKING DIAGRAM



P/N =Marking Code G =Green Compound

ΥW =Date Code F =Factory Code



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